



PMOLED display power supply

Features

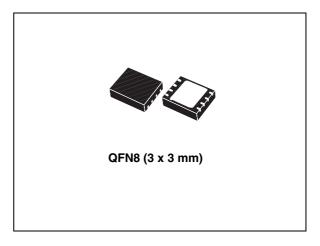
- Inductor switches boost controller
- PFM mode control
- High efficiency over wide range of load (1 mA to 40 mA)
- Integrated load disconnect switch
- Over voltage protection with automatic restart
- Soft start with adjustable peak current limit
- Enable pin
- Low shutdown current
- Small external inductor
- Supply voltage from 3.0 V to 5.5 V

Application

■ PMOLED display driver

Description

STOD2540 is dedicated to passive matrix OLED (PMOLED) displays for portable handsets and provides the pre-charge and biasing voltage of the column matrix driver as shown in figure 3. The current capability of STOD2540 allows feeding a 1", 1.3" or 1.5" color PMOLED. STOD2540 is a boost converter that operates from 3.0 V to 5.5 V and can provide an output voltage as high as 25 V. The output current capability is maximum 40 mA up to 25 V output voltage. The regulation is performed by a resistor divider network (figure 3) that detects the output voltage.



In this state-of-the-art boost converter, a DC current path exists between the battery source and the load. In order to reduce the consumption in shutdown mode, a high-side load isolation switch is necessary to cut this DC current path in standby mode. The load disconnect switch (LDS) act as an isolation switch in shutdown mode.

Table 1. Device summary

Order code	Package	Packaging
STOD2540PUR	QFN8 (3 x 3 mm)	3000 parts per reel

Contents STOD2540

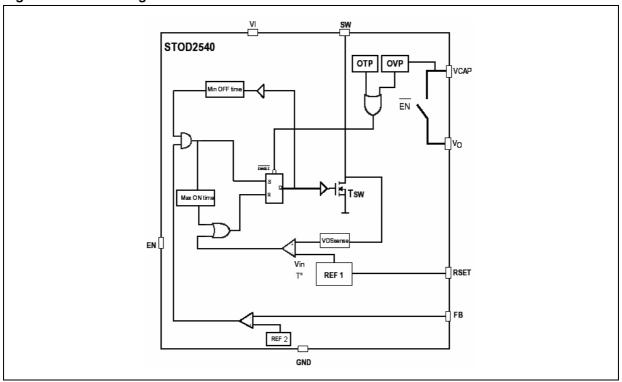
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STOD2540 Diagram

1 Diagram

Figure 1. Block diagram



Pin configuration STOD2540

2 Pin configuration

Figure 2. Pin connections (top through view)

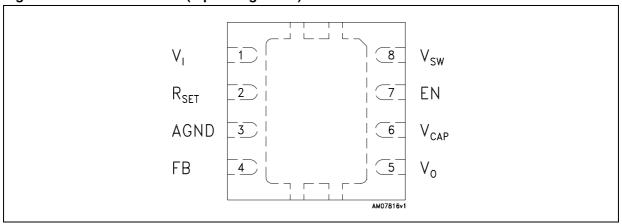


Table 2. Pin description

Pin n°	Symbol	Note
1	VI	Supply voltage
2	R _{SET}	Peak inductor current adjust
3	AGND	Analog ground
4	FB	Feedback for the LED current regulation
5	V _O	Output voltage for LED supply
6	V _{CAP}	Load disconnect switch input
7	EN	IC enable signal
8	V _{SW}	Boost switch drain
	PGND	Power ground

STOD2540 Maximum ratings

3 Maximum ratings

Table 3. Absolute maximum ratings

Symbol	Parameter	Value	Unit
VB _{SW} , VB _O	Breakdown voltage at OUT and SW pin	40	V
V _I	Supply voltage range	6	V
R _{SET}	R _{SET} pin	V _I + 0.3	٧
EN	Enable pin	V _I + 0.3	V
V _{ESD}	ESD ratings, HBM MIL STD 883C	2	kV
T _{STG}	Storage temperature range	- 65 to 150	°C
T _{OP}	Operating junction temperature range	- 40 to 85	°C

Table 4. Thermal data

Symbol	Parameter	Value	Unit
R _{thJA}	Thermal resistance junction-ambient	52	°C/W

Electrical characteristics STOD2540

4 Electrical characteristics

 T_J = 40 °C to 85 °C, V_I = 3.6 V, V_{EN} = 3V, C_I = C_O = 4.7 $\mu F,$ L = 4.7 $\mu H,$ R_1 = 180 k $\Omega,$ R_2 = 10 k $\Omega,$ V_O = 24 V, Typ. values @ 25 °C, unless otherwise specified.

Table 5. Electrical characteristics

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit	
VI	Input voltage range		3.0		5.5	V	
V _O	Regulated output voltage	V _I = 3 V to 5.5 V	V _I + 0.5	25	35	V	
V _{OVP}	Over voltage protection on output		35			V	
Io	Continuous output current	V _O = 25 V	1		40	mA	
1	Ctand by augrent	V _{EN} = Low, V _I = 3.6 V			3		
I _{SD}	Stand-by current	V _{EN} = Low, V _I = 3 V to 4.2 V			10	μΑ	
	Out a seed our want as a seed out to	V _I = 3 V to 4.2 V @ 25 °C		0.4	0.8	A	
ΙQ	Quiescent current consumption	V _I = 5.5 V @ 25 °C		0.8	1.2	mA	
R _{DSON-SW}	Boost switch R _{DSON} (1)	V _I = 4.2 V, I _{SW} = 100 mA		0.4		Ω	
1 DSON-SW	BVDS Breakdown voltage		40			V	
R _{DSON-} LDS	R _{DSON} (1)	V _O = 25 V, I _O = 30 mA		2		Ω	
I IDSON-LDS	BVDS Breakdown voltage		40			V	
I _{LIM-ADJ}	Peak inductor limit range (1)	R_{SET} = 10 kΩ to 100 kΩ	0.2		1.1	Α	
I _{LIM-MAX}	Maximum peak inductor current (1)	V _I = 3 V to 5.5 V, R _{SET} = V _I	0.75		1.2	А	
FB	Feedback voltage	5% @ 25 °C	1.18	1.24	1.30	V	
T _{ON_MAX}	Maximum ON time	V _I = 4.2 V		5.5		μs	
T _{OFF_MIN}	Minimum OFF time	V _I = 4.2 V		300		ns	
	Efficiency, V _I = 3.6 V ⁽¹⁾	$I_O = 1 \text{ mA to 5 mA}$	65				
Eff	Efficiency, $v_1 = 3.0 \text{ V}$	I _O = 5 mA to 40 mA	70				
EII	Efficiency V 4.2 V (1)	I _O = 1 mA to 5 mA	65			%	
	Efficiency, $V_1 = 4.2 V^{(1)}$	I _O = 5 mA to 40 mA	70				
		$V_1 = 3.6 \text{ V}, I_0 = 5 \text{ mA}, V_0 = 24 \text{ V}$		1.3			
Ripple	Output visuals and naise	$V_1 = 3.6 \text{ V}, I_O = 30 \text{ mA}, V_O = 24 \text{ V}$		1.3		0/	
	Output ripple and noise	$V_1 = 4.2 \text{ V}, I_0 = 5 \text{ mA}, V_0 = 24 \text{ V}$		1.3		- %	
		V _I = 4.2 V, I _O = 30 mA, V _O = 24 V		1.3			
OV _{HYST}	Over-voltage hysteresis			2		V	

Table 5. Electrical characteristics (continued)

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit	
V _{EN}	Enable input logic low	Disable Low V _{IL}			0.3	V	
V EN	Enable input logic high	Enable High V _{IH}	1.2]	
Line_V _{FB}	Line regulation V _{FB}	$V_1 = 3 \text{ V to } 5.5 \text{ V, } I_O = 5 \text{ mA}$		5	35	mV	
Load_V _{FB}	Line regulation V _{FB}	$V_1 = 3 \text{ V to } 5.5 \text{ V, } I_O = 5 \text{ mA}$		5	35	mV	

^{1.} Guaranteed by design.

5 Functional description

5.1 Boost controller

STOD2540 is a boost converter operating in PFM (pulsed frequency modulation) mode. The converter monitors the output voltage through the bridge resistor divider $\rm R_1$ and $\rm R_2$ and when the feedback voltage falls below the reference voltage, REF2, the boost switch $\rm t_{SW}$ turns ON and the current ramps up. The inductor current is measured by detect the temperature compensated drain voltage of the boost MOSFET. The boost turns off when its drain voltage reaches the reference REF1, the main switch remains off until the minimum off time (300 ns typical) has passed and the feedback voltage is below the reference again. A maximum ON time of 4 μs prevent the switch $\rm t_{SW}$ to stay ON during a too long period of time.

In order to well calculate the bridge resistors values with a fixed V_O , the following formula can be used:

$$(V_O / 1.24) - 1 = R_1 / R_2$$

5.2 Adjustable peak inductor current limit

The peak inductor current is monitored by sensing the drain voltage of the switch t_{SW}.

Since it exceeds the temperature compensated and supply voltage compensated reference REF1, the RS flip flop is reset and t_{SW} is turned OFF.

By connecting a resistance between the pin R_{SET} and GND, the peak current limit can be adjusted from 200 mA to 1.1 A (R_{SET} from 10 k Ω). When the pin R_{SET} is directly connected to V_I, the default value is 1 A.

5.3 Enable

The ENABLE pin is a high logic input signal and allows turning on/off the controller without cutting the input voltage from the boost regulator circuit. With a high input voltage (1.2 V < $V_{EN} < V_{I} + 0.3$ V) on this pin, the device is allowed to work normally. No pull-up or pull down is present on this pin.

5.4 **OVP**

If the regulation loop is cut, there is no signal at the feedback pin, the PFM controller will then continue to switch without control and generate an output voltage at the SW, V_{CAP} and V_{O} pin exceeding the breakdown value V_{BSW} , V_{BCAP} and V_{BO} .

The over voltage protection (OVP) senses the voltage at the V_{CAP} pin. When the voltage exceed the breakdown voltage of the device the controller is automatically turned off.

A hysteresis control enables the device to automatically restart when the output voltage drops below a 2 V typical value.

5.5 Load isolation switch

When the device is in shutdown mode, a DC current path always exists between the power source and the load; increasing the standby consumption. A high side switch LDS isolates the load from the source when the STOD2540 is disabled.

5.6 Efficiency

The total consumption of some PMOLED display, can be as low as 1 mA. In order to increase the battery run time of the device, STOD2540 offers a high efficiency over a wide range of load and input voltage range.

5.7 Under voltage lockout (UVLO)

The minimum supply voltage is 3.0 V, under this value the under voltage lockout circuit operates with typical threshold 2.8 V.

When supply voltage is below 3.0 V, possible noise in the supply line could disturb the UVLO circuit causing loss of output regulation. This behavior is eliminated choosing C_l = 10 μF or higher.

Typical application STOD2540

6 Typical application

Figure 3. Basic connection

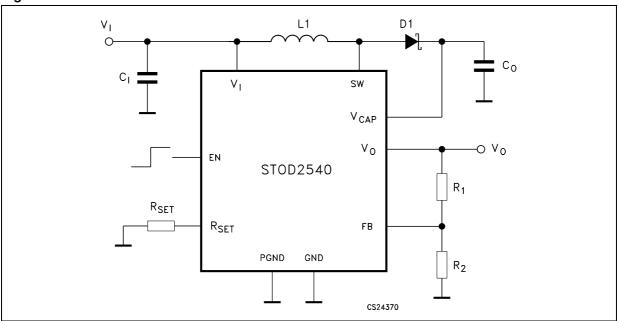


Table 6. External components (see Figure 3)

Symbol	Parameter	Test	Min.	Тур.	Max.	Unit	
		VRRM	30			V	
D	Boost schottky diode	V_F at I_F = 300 mA, T_J = 25 °C			0.5	V	
		I_R at V_R = 10 V, T_J = 25 °C			30	μΑ	
R ₁	Feedback resistor			180			
R ₂	Feedback resistor			10		kΩ	
R _{SET}	Peak current limit adjust	I _{PK} = 200 mA to 1.1 A	A 10 100				
C _I	Input ceramic type low ESR	Ceramic type		4.7		μF	
		Capacitance	4.7			μF	
Co	Output capacitance: ceramic low ESR	Voltage	42			V	
		ESR			1.6	W	
	Boost inductor (height < 2mm)	Inductance			4.7	μH	
L	boost inductor (fleight < 2mm)	I _{SAT} , R _{SET} pin to V _I			1	Α	

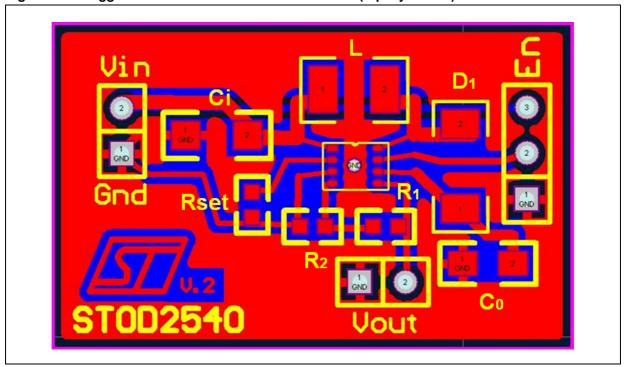
Note:

The external components suggested in this document should be considered as a design reference guide. The performances mentioned in the electrical characteristics table are not guaranteed for all the possible electrical parameters of the components included in this list. On other hand, the operation of STOD2540 is not limited to the use of components included in this list.

STOD2540 Typical application

6.1 Demonstration board

Figure 4. Suggested demonstration board schematic (top layer view)



7 Typical performance characteristics

 $I_0(mA)$

 T_J = 40 °C to 85 °C, V_I = 3.6 V, V_{EN} = 3 V, C_I = C_O = 4.7 μF, L = 4.7 μH, R_1 = 180 kΩ, R_2 = 10 kΩ, V_O = 24 V, Typ. values @ 25 °C, unless otherwise specified.

Figure 5. Efficiency vs. output current

ν(%) V_I = 5V $V_1 = 4.5 V$ 90 $V_1 = 5.5$ 80 70 $V_1 = 3V$ $V_1 = 3.5 V$ $\dot{V}_1 = 4V$ 60 50 40 30 20 10 V_{EN} =3V, R_{SET} = V_{I} , I_{O} =3 to 40mA

20

Figure 6. Efficiency vs. input voltage

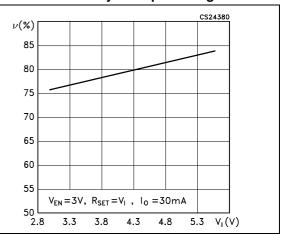


Figure 7. V_{EN} vs. temperature

10

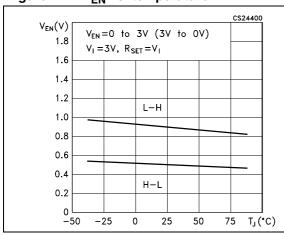


Figure 8. V_{FB} vs. input voltage

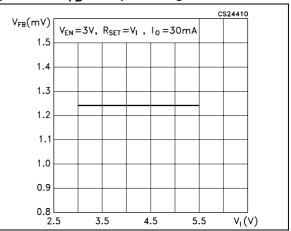


Figure 9. V_{FB} vs. output current

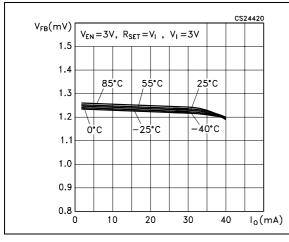
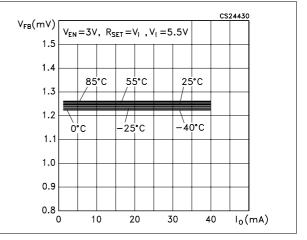


Figure 10. V_{FB} vs. output current



477

Figure 11. V_{OVP} vs. temperature

CS24440 $V_{OVP}(V)$ $V_{EN} = 3V$, $R_{SET} = V_I$, $R_1 = not$ Connected $V_1 = 4.2V$ 42 41 OVP_Max 40 39 OVP_Min 38 37 -50 -25 0 T_J (°C) 25 50 75

Figure 12. V_{RIPPLE} vs. input voltage

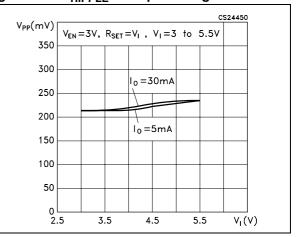


Figure 13. I_{LIM_MAX} vs. input voltage

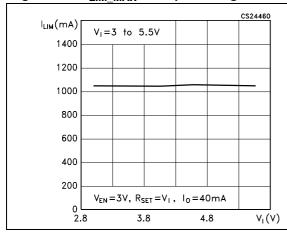


Figure 14. I_{LIM_MAX} vs. temperature

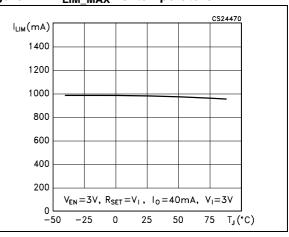


Figure 15. I_{LIM MAX} vs. R_{SET}

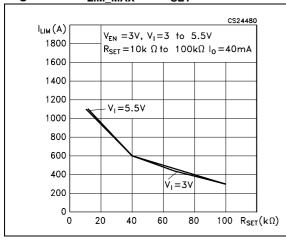


Figure 16. I_Q vs. temperature

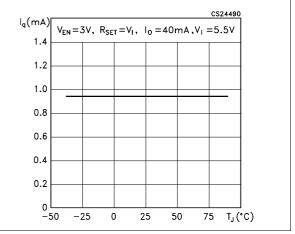


Figure 17. t_{ON_MAX} vs. temperature

T_{ON_MAX}(µs)

V_{EN}=3V, R_{SET}=V₁, I₀=40mA,V₁=4.2V

7
6
5
4
3
2
1
L=33µH

75 T_J (°C)

Figure 18. t_{OFF_MIN} vs. temperature

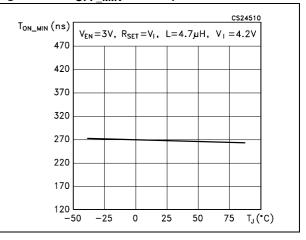


Figure 19. Line V_{FB} vs. temperature

-25

0 └ -50

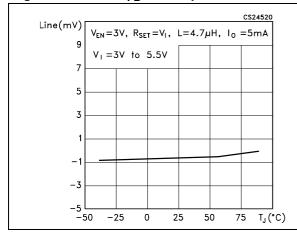
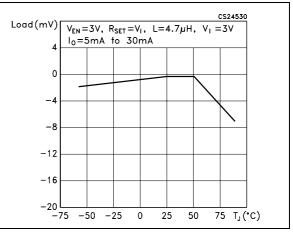


Figure 20. Load V_{FB} vs. temperature



8 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Table 7. QFN8 (3 x 3 mm) mechanical data

Dim.	mm.				
Dim.	Min.	Тур.	Max.		
А	0.80	0.90	1.00		
A1	0	0.02	0.05		
A3		0.20			
b	0.25	0.30	0.35		
D	2.85	3.00	3.15		
D2	2.49	2.64	2.74		
E	2.85	3.00	3.15		
E2	1.75	1.90	2.00		
е		0.65			
L	0.30	0.40	0.50		

BOTTOM VIEW D2 PIN 1 ID EXPOSED PAD 0.44 0.23 т 5 6 8 b (8x) // 0.1 C -*A3* SEATING PLANE A 1 C 0.08 C LEADS COPLANARITY 5 8 6 E/23 PIN 1 ID -D/2-TOP VIEW 8057023_B

Figure 21. Drawing dimension QFN8 (3 x 3 mm)

Tape & reel QFNxx/DFNxx (3x3) mechanical data

Dim.		mm.			inch.	
Dilli.	Min.	Тур.	Max.	Min.	Тур.	Max.
А			180			7.087
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		
Т			14.4			0.567
Ao		3.3			0.130	
Во		3.3			0.130	
Ko		1.1			0.043	
Po		4			0.157	
Р		8			0.315	

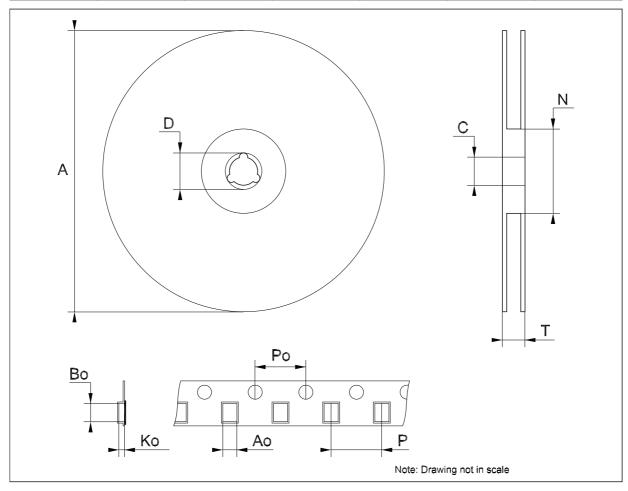


Figure 22. QFN8 (3x3) footprint recommended data

STOD2540 Revision history

9 Revision history

Table 8. Document revision history

Date	Revision	Changes
22-Mar-2006	1	Initial release.
03-Apr-2006	2	Add fig. 2 demonstration board on page 3.
08-Jun-2006	3	Description in cover page updated.
23-Jun-2006	4	Change range of R _{SET} value and add description paragraph 5.7.
11-Sep-2006	5	Mistake on table 4 Ripple test value 3.6 V ==> 4.2 V.
27-Feb-2009	6	Modified mechanical data.
03-Mar-2009	7	Modified packaging Table 1 on page 1.
11-Mar-2009	8	Modified Figure 2 on page 4 and added Figure 22 on page 18.
25-Nov-2009	9	Modified Table 1 on page 1.
01-Jul-2010	10	Modified: Table 7 on page 15, Figure 21 on page 16 and Figure 22 on page 18.

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